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BC307B

Amplifier Transistors

PNP Silicon

Features

- This is a Pb-Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V_{CEO}	-45	Vdc
Collector – Base Voltage	V_{CBO}	-50	Vdc
Emitter – Base Voltage	V_{EBO}	-5.0	Vdc
Collector Current – Continuous	I_C	-100	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.0 8.0	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

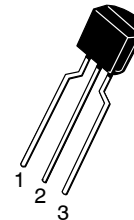
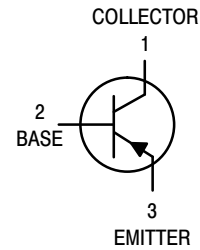
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	125	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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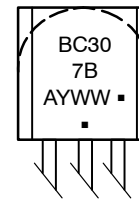
<http://onsemi.com>



TO-92
CASE 29
STYLE 17

BENT LEAD
TAPE & REEL
AMMO PACK

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
BC307BRL1G	TO-92 (Pb-Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BC307B

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = -2.0\text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	-45	-	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = -100\text{ }\mu\text{Adc}$, $I_C = 0$)	$V_{(BR)EBO}$	-5.0	-	-	Vdc
Collector–Emitter Leakage Current ($V_{CES} = -50\text{ V}$, $V_{BE} = 0$) ($V_{CES} = -50\text{ V}$, $V_{BE} = 0$) $T_A = 125^\circ\text{C}$	I_{CES}	-	-0.2	-15	nAdc μA
ON CHARACTERISTICS					
DC Current Gain ($I_C = -10\text{ }\mu\text{Adc}$, $V_{CE} = -5.0\text{ Vdc}$) ($I_C = -2.0\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$) ($I_C = -100\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	h_{FE}	-	150	-	-
		200	290	460	
		-	180	-	
Collector–Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -0.5\text{ mAdc}$) ($I_C = -10\text{ mAdc}$, $I_B = \text{see Note 1}$) ($I_C = -100\text{ mAdc}$, $I_B = -5.0\text{ mAdc}$)	$V_{CE(sat)}$	-	-0.10	-0.3	Vdc
		-	-0.30	-0.6	
		-	-0.25	-	
Base–Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -0.5\text{ mAdc}$) ($I_C = -100\text{ mAdc}$, $I_B = -5.0\text{ mAdc}$)	$V_{BE(sat)}$	-	-0.7	-	Vdc
		-	-1.0	-	
Base–Emitter On Voltage ($I_C = -2.0\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	$V_{BE(on)}$	-0.55	-0.62	-0.7	Vdc
DYNAMIC CHARACTERISTICS					
Current–Gain–Bandwidth Product ($I_C = -10\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	-	280	-	MHz
Common Base Capacitance ($V_{CB} = -10\text{ Vdc}$, $I_C = 0$, $f = 1.0\text{ MHz}$)	C_{cbo}	-	-	6.0	pF
Noise Figure ($I_C = -0.2\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$)	NF	-	2.0	10	dB

1. $I_C = -10\text{ mAdc}$ on the constant base current characteristic, which yields the point $I_C = -11\text{ mAdc}$, $V_{CE} = -1.0\text{ V}$.

TYPICAL CHARACTERISTICS

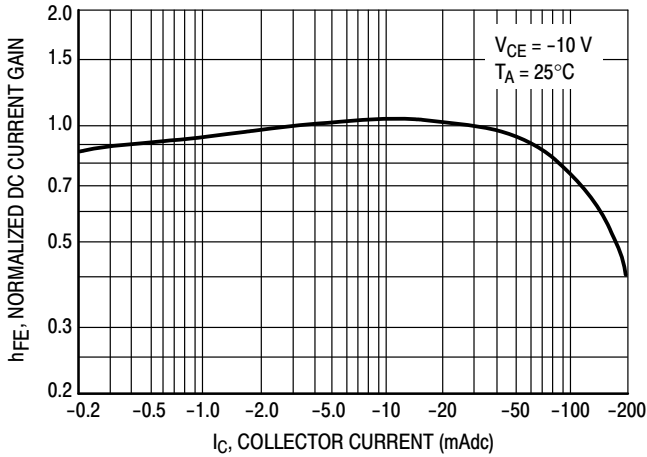


Figure 1. Normalized DC Current Gain

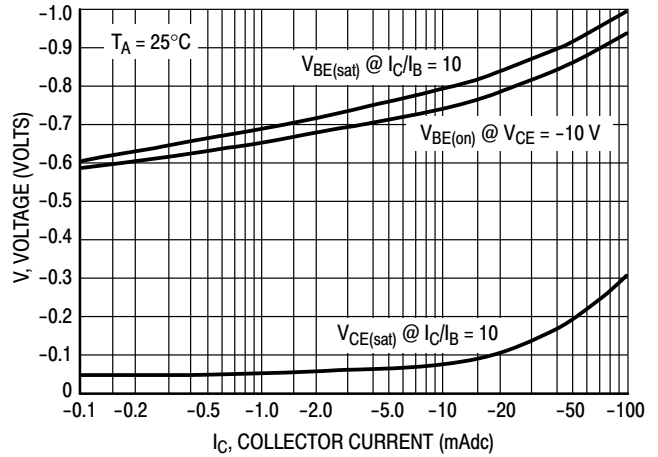


Figure 2. "Saturation" and "On" Voltages

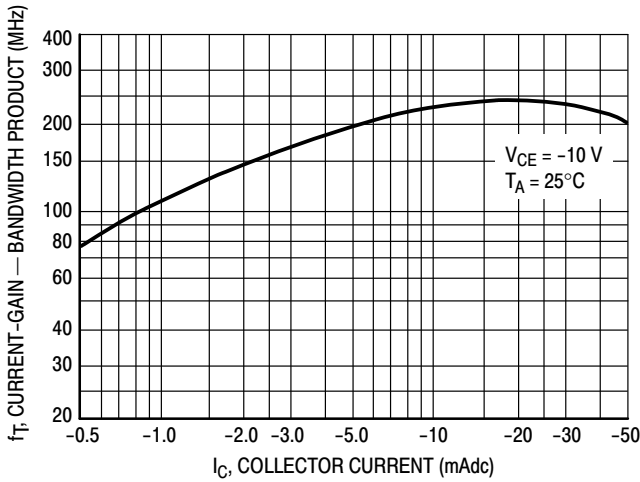


Figure 3. Current-Gain — Bandwidth Product

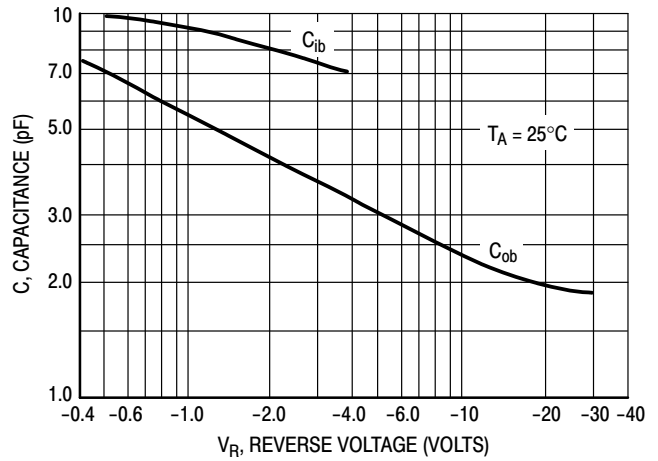


Figure 4. Capacitances

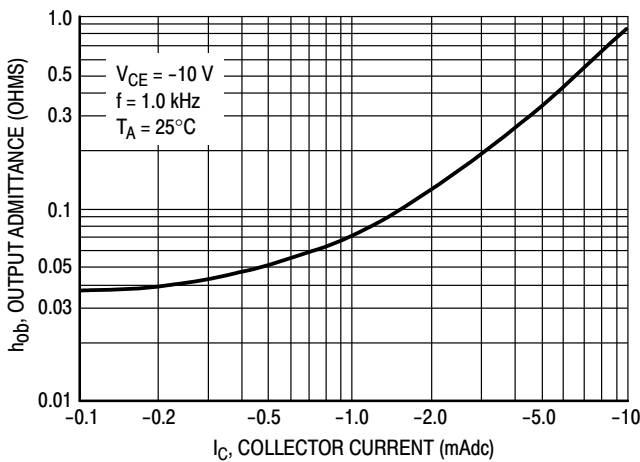


Figure 5. Output Admittance

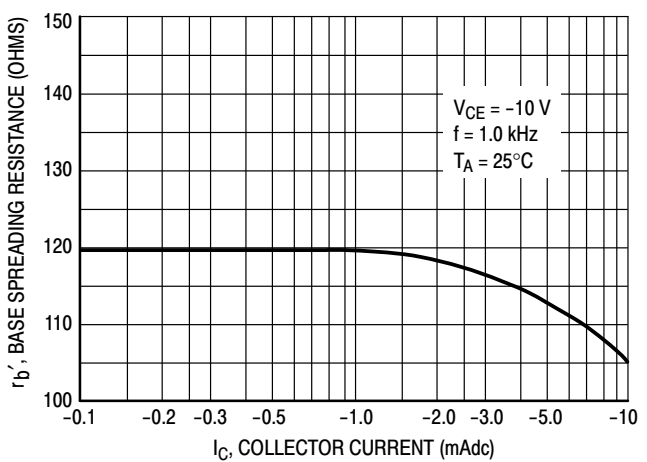
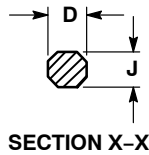
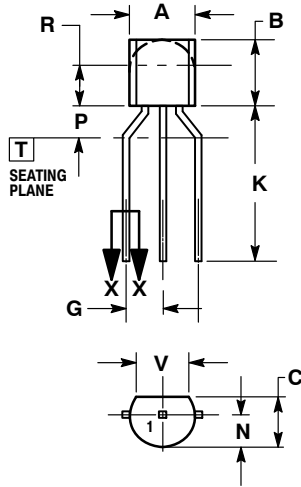


Figure 6. Base Spreading Resistance

BC307B

PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AM



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 17:

1. COLLECTOR
2. BASE
3. EMITTER

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